TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

2SJ440

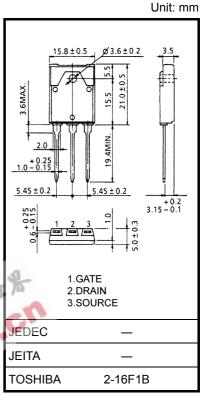
Audio Frequency Power Amplifier Application

• High breakdown voltage: $V_{DSS} = -180 \text{ V}$

• High forward transfer admittance: $|Y_{fs}| = 4.0 \text{ S (typ.)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage	V_{DSS}	-180	٧	
Gate-source voltage	V_{GSS}	±20	V	
Drain current (Note 1)	ΙD	-9	А	
Power dissipation (Tc = 25°C)	P_{D}	80	W	
Channel temperature	T _{ch}	150	°C	
Storage temperature range	T _{stg}	−55 to 150	°C	



Weight: 5.8 g (typ.)

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V _{DS} = 0, V _{GS} = ±20 V	_	_	±0.5	μΑ
Drain-source breakdown voltage	V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0$	-180	_	_	V
Gate-source cut-off voltage	V _{GS (OFF)} (Note 3)	V _{DS} = -10 V, I _D = -0.1 A	-1.4		-2.8	V
Drain-source saturation voltage	V _{DS} (ON)	$I_D = -6 \text{ A}, V_{GS} = -10 \text{ V}$	_	-1.5	-5.0	V
Forward transfer admittance	Y _{fs}	$V_{DS} = -10 \text{ V}, I_D = -3 \text{ A}$	_	4.0	-	S
Input capacitance	C _{iss}	$V_{DS} = -30 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	1300	_	pF
Output capacitance	Coss	$V_{DS} = -30 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	350	_	pF
Reverse transfer capacitance	C _{rss}	$V_{DS} = -30 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	200	_	pF

Note 3: $V_{GS (OFF)}$ classification Y: -1.4 to -2.8

This transistor is the electrostatic-sensitive device. Plese handle with caution.

Marking



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